NSN 5961-00-004-5855

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View Online at https://aerobasegroup.com/nsn/5961-00-004-5855 **Inclosure Material:** Metal **Overall Length:** Between 0.480 inches and 0.535 inches Overall Diameter: 0.535 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.855 inches and 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 86.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life:

Demilitarization:

Unit Of Measure:

N/a

No

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